



STPR120A

HIGH EFFICIENCY FAST RECOVERY DIODE

Table 1: Main Product Characteristics

$I_{F(AV)}$	1 A
V_{RRM}	200 V
$T_j(\text{max})$	150°C
$V_F(\text{max})$	0.74 V
$t_{rr}(\text{max})$	35 ns

FEATURES AND BENEFITS

- Very low switching losses
- Low forward voltage drop
- Fast rectifier Epitaxial diode
- Surface mount package

DESCRIPTION

Single chip rectifier suited to Switched Mode Power Supplies and high frequency DC/DC converters.

Packaged in SMA, this surface mount device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

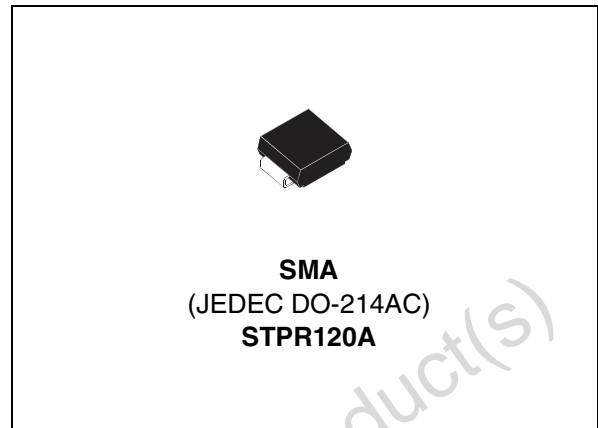


Table 2: Order Code

Part Number	Marking
STPR120A	R12

Table 3: Absolute Ratings (in limiting values)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	200	V
$I_{F(RMS)}$	RMS forward current	8	A
$I_{F(AV)}$	Average forward current	1	A
I_{FSM}	Surge non repetitive forward current	30	A
T_{stg}	Storage temperature range	-65 to + 150	°C
T_j	Maximum operating junction temperature	150	°C

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Table 4: Thermal Resistance

Symbol	Parameter	Value	Unit
$R_{th(j-l)}$	Junction to lead	30	°C/W

Table 5: Static Electrical Characteristics

Symbol	Parameter	Tests conditions	Min.	Typ	Max.	Unit
I_R^*	Reverse leakage current	$T_j = 25^\circ\text{C}$			3	μA
		$T_j = 125^\circ\text{C}$			180	
V_F^{**}	Forward voltage drop	$T_j = 25^\circ\text{C}$			0.94	V
		$T_j = 150^\circ\text{C}$			0.69	

Pulse test: * $t_p = 5 \text{ ms}$, $\delta < 2\%$

** $t_p = 380 \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation: $P = 0.62 \times I_{F(AV)} + 0.12 I_F^2(\text{RMS})$

Table 6: Recovery Characteristics

Symbol	Parameter	Test conditions	Min.	Typ	Max.	Unit
t_{rr}	Reverse recovery time	$T_j = 25^\circ\text{C}$			25	ns
		$I_F = 0.5\text{A}$ $I_{rr} = 0.25\text{A}$ $I_R = 1\text{A}$ $I_F = 1\text{A}$ $di_F/dt = 50 \text{ A}/\mu\text{s}$ $V_R = V_{RRM}$			25	
t_{fr}	Forward recovery time	$T_j = 25^\circ\text{C}$			25	ns
V_{FP}	Forward recovery voltage	$T_j = 25^\circ\text{C}$			5	V

Figure 1: Average forward power dissipation versus average forward current

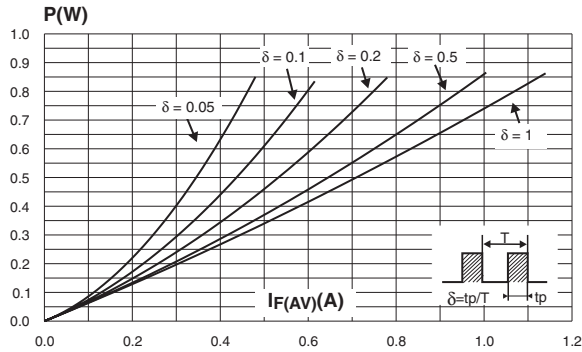


Figure 2: Peak current versus form factor

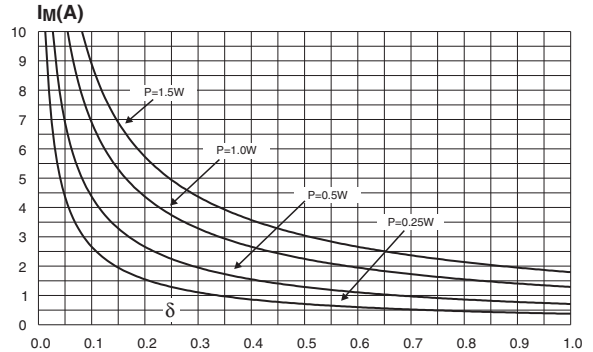


Figure 3: Average forward current versus ambient temperature (delta = 0.5)

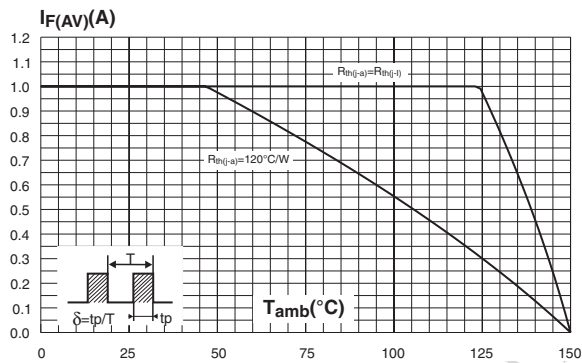


Figure 4: Non repetitive surge peak forward current versus overload duration

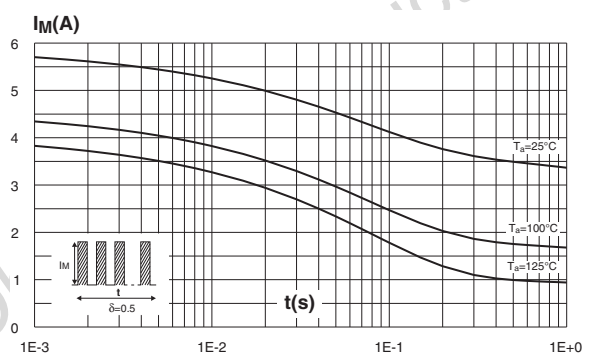


Figure 5: Variation of thermal impedance junction to ambient versus pulse duration (epoxy printed circuit board, e(Cu)=35µm, recommended pad layout)

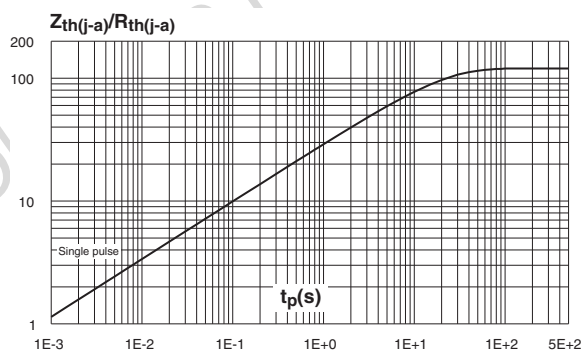


Figure 6: Forward voltage drop versus forward current (maximum values)

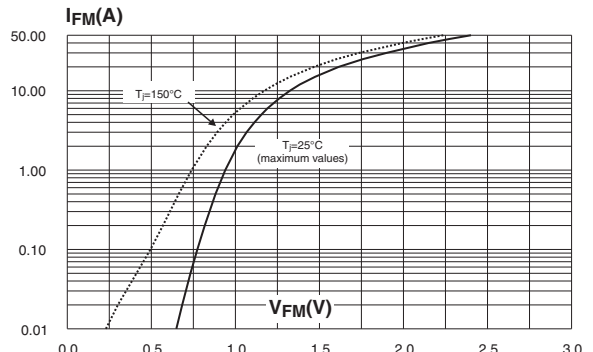


Figure 7: Junction capacitance versus reverse voltage applied (typical values)

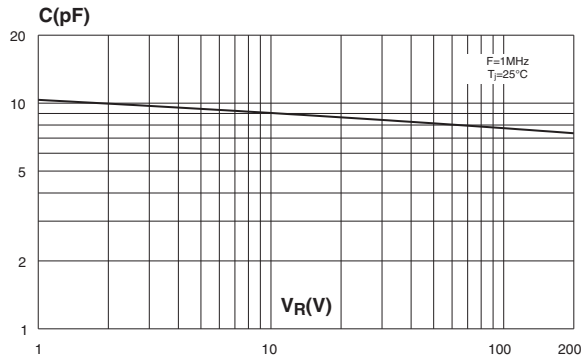


Figure 8: Recovery charges versus di_F/dt

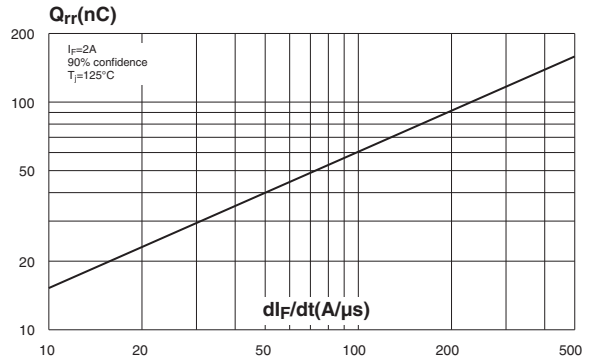


Figure 9: Peak recovery current versus di_F/dt

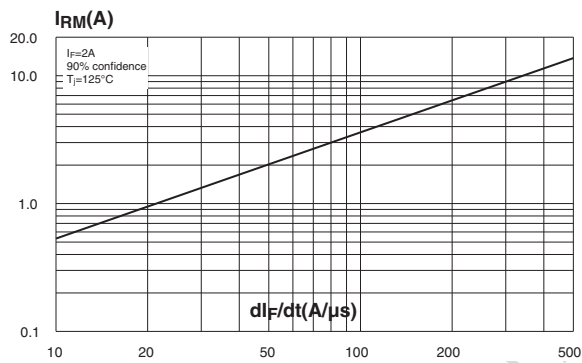


Figure 10: Dynamic parameters versus junction temperature

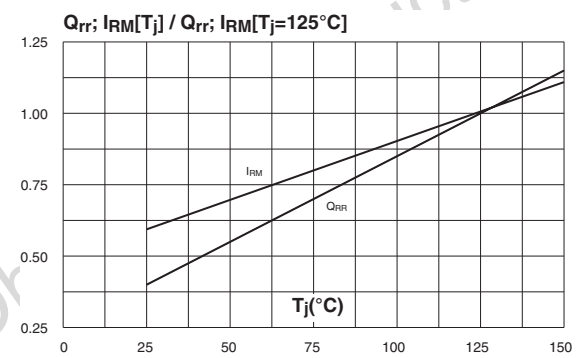
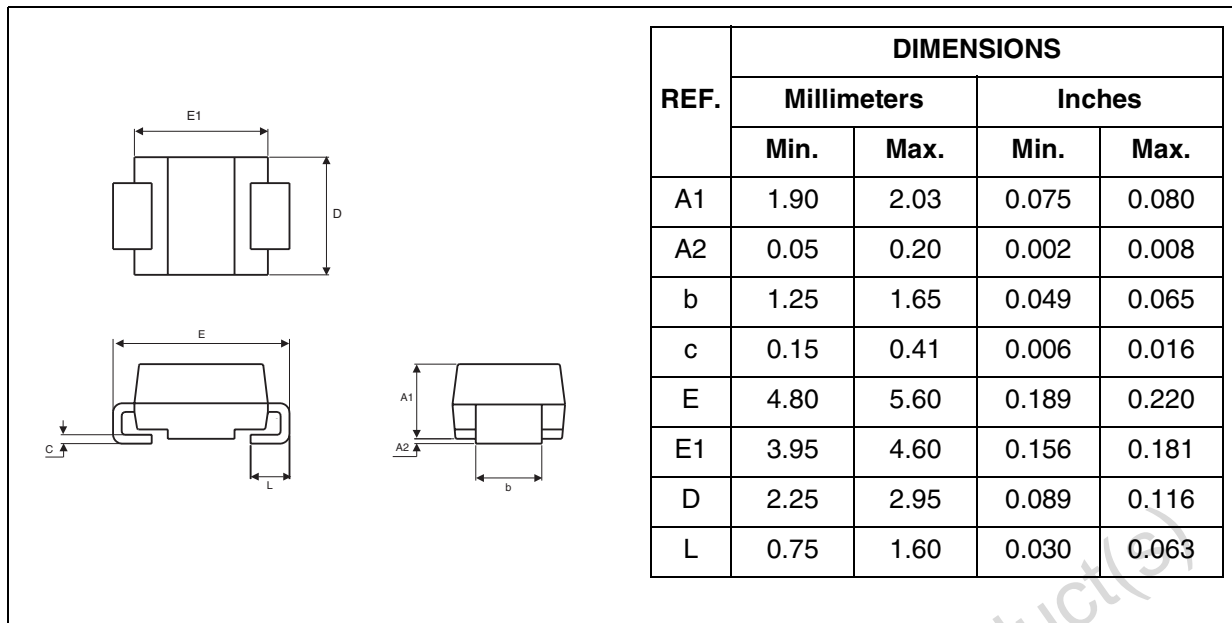
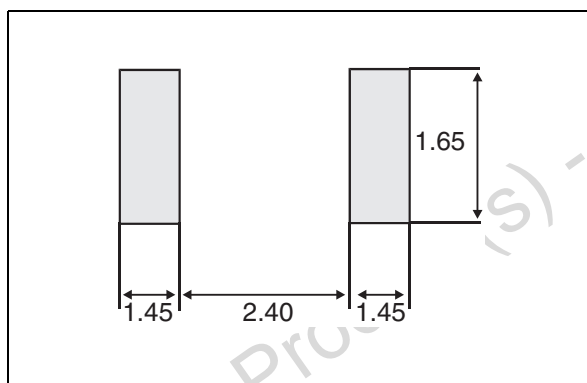


Figure 11: SMA Package Mechanical Data

Figure 12: SMA Foot Print Dimensions
(in millimeters)

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Table 7: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPR120A	R12	SMA	0.068 g	5000	Tape & reel

- Band indicates cathode
- Epoxy meets UL94, V0

Table 8: Revision History

Date	Revision	Description of Changes
Jul-2003	3	Last update.
Aug-2004	4	SMA package dimensions update. Reference A1 max. changed from 2.70mm (0.106inc.) to 2.03mm (0.080).

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